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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09.189,098	11.709.71998	ALAN R. REINBERG	3528US-(97-1	5116
5	2590 03 12 2003			
TRASK BRITT & ROSSA			EXAMINER	
P O BOX 2550 SALT LAKE CITY, UT 84110			WEISS, HOWARD	
			ART UNIT	PAPER NUMBER
		2011		

DATE MAILED: 03/12/2003

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applic (
	09/189.098	REINBERG, ALAN R
Office Action Summary	Examiner	Art Unit
	Howard Weiss	2814
The MAILING DATE of this communication app		
Period for Reply		
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION. Extensions of fine may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. If the period for reply specified above is less than thirty (30) days, a reply. If NO period for reply is specified above, the maximum statutory period w. Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b) Status	within the statutory minimum of thirty (3 till apply and will expire SIX (6) MONTH: cause the application to become ABAN	be timely filed O) days will be considered timely. S from the mailing date of this communication DONED (35 U.S.C. § 133).
1) Responsive to communication(s) filed on <u>27 J</u>	<u>anuary 2003</u> .	
2a)☑ This action is FINAL . 2b)☐ Thi	s action is non-final.	
3) Since this application is in condition for allowa closed in accordance with the practice under the		
Disposition of Claims		
4) Claim(s) 1-20 and 32-71 Nate pending in the		
4a) Of the above claim(s) is/are withdray	vn from consideration.	
5) Claim(s) is/are allowed.		
6)⊠ Claim(s) <u>1-20 and 32-71</u> ls /are rejected.		
7) Claim(s) is/are objected to.		
8) Claim(s) are subject to restriction and/or	election requirement.	
Application Papers		
9) The specification is objected to by the Examiner		
10)⊠ The drawing(s) filed on <u>27 January 2003</u> ½ /are:		
Applicant may not request that any objection to the		
11) The proposed drawing correction filed on		approved by the Examiner
If approved corrected drawings are required in rep		
12) The oath or declaration is objected to by the Exa	an milei.	
Priority under 35 U.S.C. §§ 119 and 120		40(-) (-) (6)
13) Acknowledgment is made of a claim for foreign	priority under 35 U.S.C. § 1	19(a)-(d) of (i).
a) ☐ All b) ☐ Some * c) ☐ None of:		
1. Certified copies of the priority documents		e N
2. Certified copies of the priority documents		
3. Copies of the certified copies of the prior application from the International Bur* See the attached detailed Office action for a list of the prior action for a list	eau (PCT Rule 17.2(a)).	
14) Acknowledgment is made of a claim for domestic	priority under 35 U.S.C. §	119(e) (to a provisional application)
a) ☐ The translation of the foreign language pro 15)☐ Acknowledgment is made of a claim for domesti		
Attachment(s)		
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449) Paper No(s)	5) Notice of Info	nmary (PTO-413) Paper No(s) rmal Patent Application (PTO-152)
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2017

Attorney's Docket Number: 3528US-(97-1099)

Filing Date: 11/9/98

Continuing Data: RCE established 2/21/01 and 6/14/02

Claimed Foreign Priority Date: none

Applicant(s): Reinberg

Examiner: Howard Weiss

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Claim Rejections - 35 USC § 103

1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

- (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Initially, and with respect to Claims 32 to 38, 70 and 71, note that a "product by process" claim is directed to the product per se, no matter how actually made. See In re Thorpe et al., 227 USPQ 964 (CAFC, 1985) and the related case law cited therein which make it clear that it is the final product per se which must be determined in a "product by process" claim, and not the patentability of the process, and that, as here, an old or obvious product produced by a new method is not patentable as a product, whether claimed in "product by process" claims or not. As stated in Thorpe,

even though product-by-process claims are limited by and defined by the process, determination of patentability is based on the product itself. *In re Brown.* 459 F.2d 531, 535, 173 USPQ 685, 688 (CCPA 1972); *In re Pilkington.* 411 F.2d 1345, 1348, 162 USPQ 145, 147 (CCPA 1969); *Buono v. Yankee Maid Dress Corp.*, 77 F.2d 274, 279, 26 USPQ 57, 61 (2d. Cir. 1935).

Note that Applicant has burden of proof in such cases as the above case law makes clear.

3. Claims 1 to 6, 8 to 10, 32 to 38, 68 and 70 are rejected under 35 U.S.C. § 103(a) as obvious over Brown et al. (U.S. Patent No. 5,792,594) and Buiguez et al. (U.S. Patent No. 4,770,977).

Brown et al. show most aspects of the instant invention (e.g. Figure 4 and Column 8 Lines 3 to 47) including:

- an intermediate conductive layer 22 made of a refractory metal (nickel and palladium; Column 6 Lines 39 and 40) in electrical and physical contact with a structure 12 of a semiconductor device, said structure located at a lower level than a protective, dielectric layer 14,18
- an electrically conductive contact layer 26 in electrical contact with said intermediate conductive layer
- an electrical and thermal insulator component 14a, 34 made of resin and enveloped and sandwiched between said intermediate conductive and electrically conductive contact layers
- said intermediate conductive layer and the contact layer abutting said protective,
 dielectric layer

Brown et al. specify that the protective, dielectric layers be photosensitive resin (i.e. polymers) but does not explicitly state that these layers contain silicon. Buiguez et al. teach to use silicon-containing, photosensitive polymers because it makes it easy and cost effect to perform (Column 2 Lines 47 to 63). It would have been obvious to a person of ordinary skill in the art at the time of invention to use silicon-containing, photosensitive polymers as taught by Buiguez et al. in the device of Brown et al. because it makes it easy and cost effect to perform.

As to the grounds of rejection under "product by process", how the contact is made does not affect the final device structure. See MPEP § 2113 which discusses the handling of "product by process" claims.

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The Specification contains no disclosure of either the critical nature of the claimed arrangement or any unexpected results arising therefrom (the Specification only mentions preferred values). Where patentability is said to be based upon particular chosen dimensions or upon another variable recited in a claim, the applicant must show that the chosen dimensions are critical. *In re Woodruff*, 919 F.2d 1575, 1578, 16 USPQ2d 1934, 1936 (Fed. Cir. 1990). Since the Applicant has not established the criticality of the thicknesses of the intermediate conductive layer and the contact layer and since these thicknesses are in common use in similar devices in the art, it would have been obvious to one of ordinary skill in the art to use these values for the stated layers in the device of Brown et al.

4. Claim 11 is rejected under 35 U.S.C. 103(a) as being unpatentable over Brown et al. and Buiguez et al., as applied to Claim 1 above, and in further view of Whitten et al. (U.S. Patent No. 5,451,811)

Brown et al. and Buiguez et al. disclose the claimed invention (Paragraph 3) except that the contact layer comprises copper instead of at least one of a refractory metal, a refractory metal nitride and aluminum. Whitten et al. teach (Column 4 Lines 55 to 57) that refractory metals (i.e. titanium-tungsten and molybdenum) are equivalent conductive materials known in the art. Therefore, because these conductors were art-recognized equivalents at the time the invention was made, one of ordinary skill in the art would have found it obvious to substitute refractory metals for copper.

5. Claims 7, 12 to 19, 39 to 54, 56 to 66, 69 and 71 are rejected under 35 U.S.C. 103(a) as being unpatentable over Ovshinsky et al. (U.S. Patent No. 5,296,716) in view of Brown et al. and Buiguez et al.

Ovshinsky et al. show most aspects of the instant invention (e.g. Figure 1) including a phase change memory element **30** located beneath the surface of an electrode **42** bearing, silicon oxide-containing layer **44**. Ovshinsky et al. does not show a contact

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for the memory element as claimed including the intermediate conductive layer, the contact layer and the insulator component enveloped by said layers. Brown et al. teach (Paragraph 3 above) to use a contact structure as claimed adjacent to the memory element (pad 12 of Brown et al. would be pad 14 of Sasaki) to reduce costs. promote high throughput and shorten cycle times (Column 2 Lines 58 to 60). It would have been obvious to a person of ordinary skill in the art at the time of invention to use the contact structure as taught by Brown et al. in the device of Ovshinsky et al. to reduce costs, promote high throughput and shorten cycle times.

Brown et al. specify that the protective, dielectric layers be photosensitive resin (i.e. polymers) but does not explicitly state that these layers contain silicon. Buiguez et al. teach to use silicon-containing, photosensitive polymers because it makes it easy and cost effect to perform (Column 2 Lines 47 to 63). It would have been obvious to a person of ordinary skill in the art at the time of invention to use silicon-containing, photosensitive polymers as taught by Buiguez et al. in the device of Ovshinsky et al. and Brown et al. because it makes it easy and cost effect to perform.

6. Claims 20, 55 and 67 rejected under 35 U.S.C. 103(a) as being unpatentable over Ovshinsky et al. in view of Brown et al. and Buiguez et al., as applied to Claims 12, 45 and 56 above, and in further view of Whitten et al.

Ovshinsky et al. in view of Brown et al. and Buiguez et al. disclose the claimed invention (Paragraph 6) except that the contact layer comprises copper instead of an al least one of a refractory metal. a refractory metal nitride and aluminum. Whitten et al. teach (Column 4 Lines 55 to 57) that refractory metals (i.e. titanium-tungsten and molybdenum) are equivalent conductive materials known in the art. Therefore, because these conductors were art-recognized equivalents at the time the invention was made, one of ordinary skill in the art would have found it obvious to substitute refractory metals for copper.

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Response to Arguments

7. Applicant's arguments with respect to Claims 1 to 20, 32 to 71 have been considered but are most in view of the new ground(s) of rejection.

In reference to the limitation of Claim 10, the express, implicit, and inherent disclosures of a prior art reference may be relied upon in the rejection of claims under 35 U.S.C. 102 or 103. "The inherent teaching of prior art reference, a question of fact, arises both in the context of anticipation and obviousness." *In re Napier, 55 F.3d 610, 613, 34 USPQ2d 1782, 1784 (Fed. Cir.1995) (affirmed a 35 U.S.C. 103 rejection based in part on inherent disclosure in one of the references).* See also In re Grasselli, 713 F.2d 731, 739, 218 USPQ 769, 775 (Fed.Cir. 1983). In the instant case, the melting point of the conductive materials in the prior art are well above any temperature required to switch a phase change component (e.g. Al has a melting temperature of 933 °K and Cu is 1356 °K). Also, the thermal insulative properties of the materials used by the prior art are an inherent property.

In view of these reasons and those set forth in the present office action, the rejections of the stated claims stand.

Conclusion

- 9. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. Lee et al.: (U.S. Patent No. 5,956,609) teach that structure can be on or in a semiconductor substrate.
- 10. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

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A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

- 11. Papers related to this application may be submitted directly to Art Unit 2814 by facsimile transmission. Papers should be faxed to Art Unit 2814 via the Art Unit 2814 Fax Center located in Crystal Plaza 4, room 3C23. The faxing of such papers must conform with the notice published in the Official Gazette, 1096 OG 30 (15 November 1989). The Art Unit 2814 Fax Center number is (703) 308-7722 or -7724. The Art Unit 2814 Fax Center is to be used only for papers related to Art Unit 2814 applications. The official TC2800 Before-Final, (703) 872-9318, and After-Final, (703) 872-9319, Fax numbers will provide the fax sender with an auto-reply fax verifying receipt of their fax by the USPTO.
- 12. Any inquiry concerning this communication or earlier communications from the examiner should be directed to **Howard Weiss** at **(703)** 308-4840 and between the hours of 8:00 AM to 4:00 PM (Eastern Standard Time) Monday through Friday or by e-mail via **Howard.Weiss@uspto.gov**.

Any inquiry of a general nature or relating to the status of this application should be directed to the **Group 2800 Receptionist** at **(703) 308-0956**.

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13. The following list is the Examiner's field of search for the present Office Action:

Field of Search	Date	
U.S. Class / Subclass(es): 257/ 530; 438/ 600, 601	thru 10/18/02	
Other Documentation: none		
Electronic Database(s): EAST	thru 10/18/02	

Howard Weiss Patent Examiner Art Unit 2814

HW/hw 7 March 2003

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